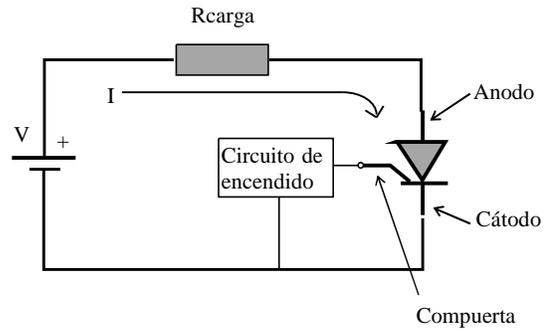
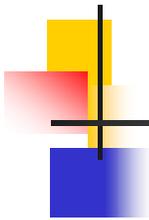
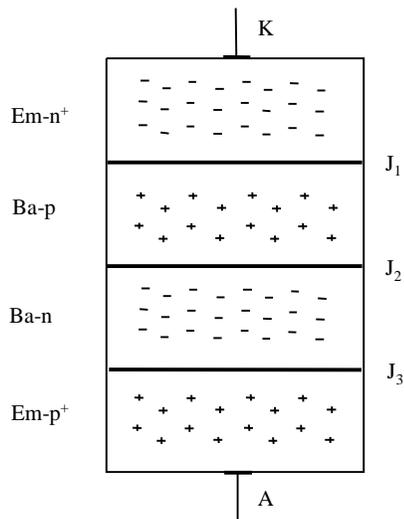


Tiristores

Función:

Estructura

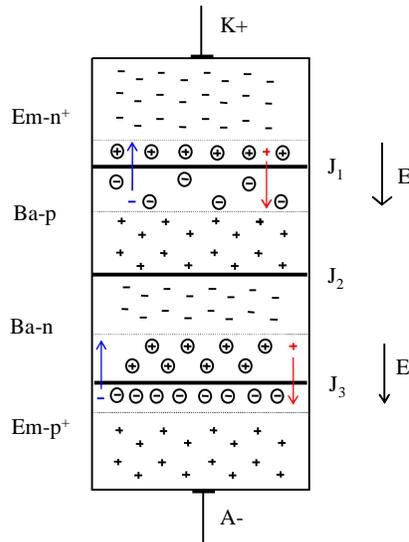


A = Anodo
K = Cátodo

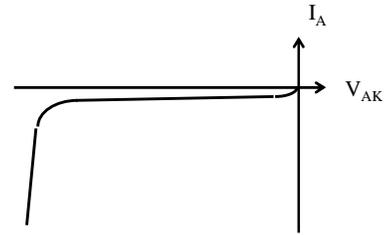
Em-n⁺ = Emisor n
Ba-p = Base-p
Ba-n = Base-n
Em-p⁺ = Emisor p

J₁ = Juntura Emisor n
J₂ = Juntura Base
J₃ = Juntura Emisor p

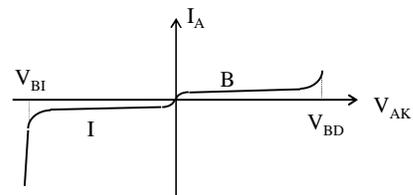
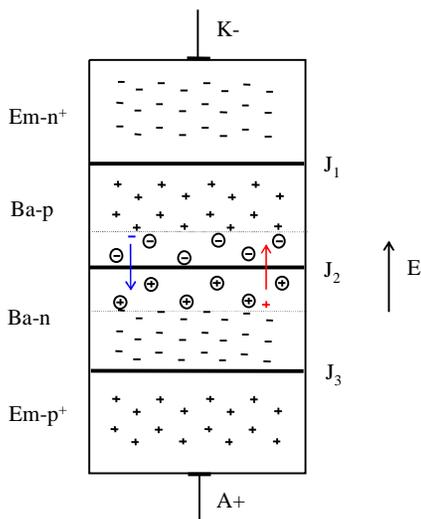
Bloqueo inverso



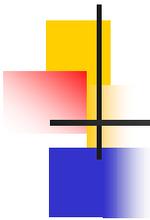
- Portadores n, mayoritarios
- + Portadores p, mayoritarios
- Portadores n, minoritarios
- + Portadores p, mayoritarios
- ⊖ Carga espacial: iones aceptores
- ⊕ Carga espacial: iones donores



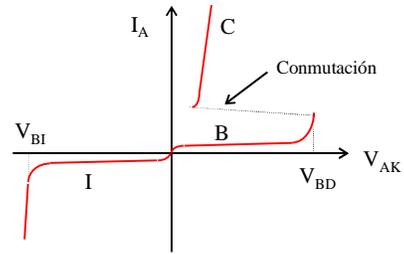
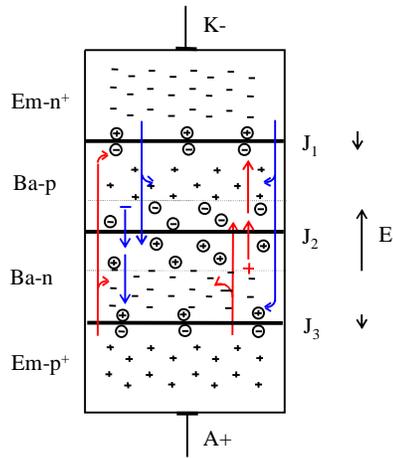
Bloqueo directo



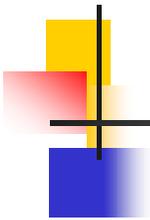
- B: Bloqueo directo
- I: Bloqueo inverso
- V_{BD} : Voltaje de bloqueo directo
- V_{BI} : Voltaje de bloqueo inverso



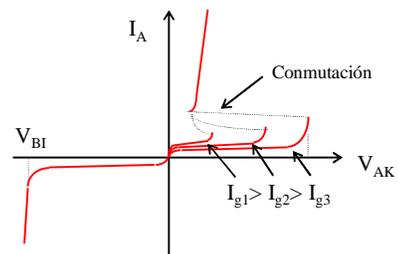
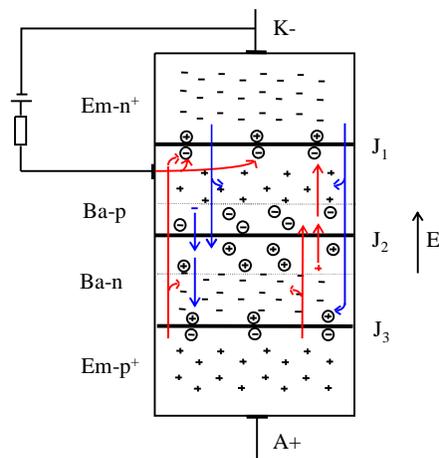
Conmutación

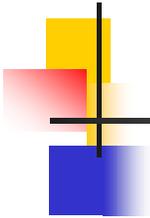


- B: Bloqueo directo
- I: Bloqueo inverso
- C: Conducción
- V_{BD} : Voltaje de bloqueo directo
- V_{BI} : Voltaje de bloqueo inverso

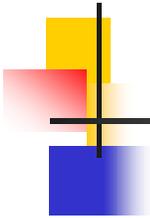
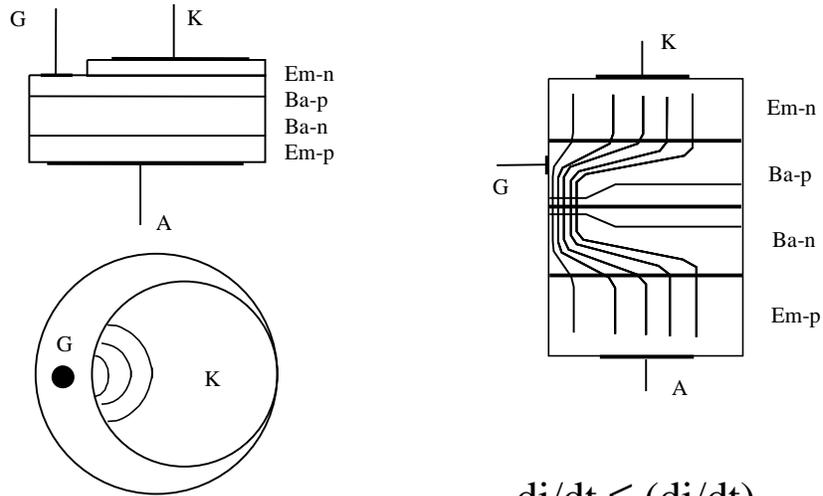


Conmutación controlada por compuerta

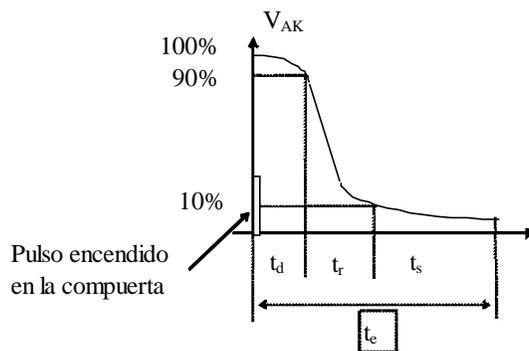
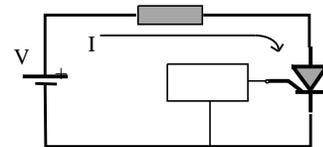




Conmutación: Transientes



Conmutación: Transientes



t_d = tiempo de retardo
 t_r = tiempo de conmutación
 t_s = tiempo de expansión
 $t_c = t_d + t_r + t_s$ tiempo de encendido

Condición de conmutación

$$I_{J3}^p = g_3 * I_A \quad \text{Eficiencia de inyección: } g_3 = \frac{I_p}{I_p + I_n}$$

$$I_{J2}^p = a_3 I_A \quad \text{con } a_3 = \alpha_T g_3$$

en que α_T es el factor de transporte

$$I_{J2}^p = a_3 I_A + I_0^p$$

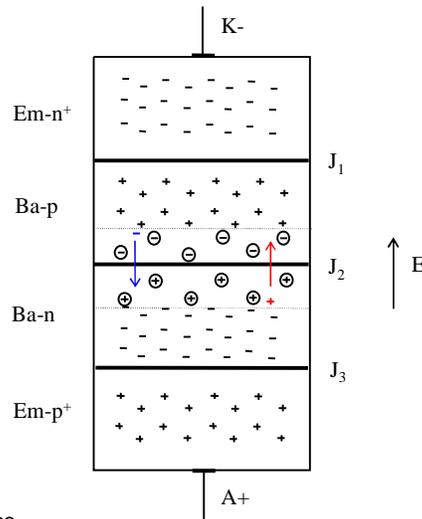
Análogamente para el flujo de electrones se tiene:

$$I_{J2}^n = a_1 I_K + I_0^n$$

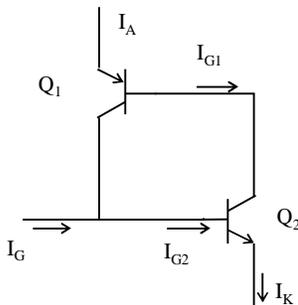
$$I_{J2}^p + I_{J2}^n = a_3 I_A + a_1 I_K + I_0^p + I_0^n$$

$$I_{J2}^p + I_{J2}^n = I_A \quad I_A = I_K$$

$$I_A = \frac{I_0^p + I_0^n}{1 - (a_3 + a_1)} \quad a_3 + a_1 = 1 \quad I_A = \infty$$



Modelo en base a transistores



$$I_{C1} = a_1 I_A + I_{C01}$$

$$I_{B1} = I_A - I_{C1} = (1 - a_1 I_A) - I_{C01}$$

$$I_{C2} = a_2 I_K + I_{C02}$$

pero $I_{B1} = I_{C2}$

$$(1 - a_1 I_A) - I_{C01} = a_2 I_K + I_{C02}$$

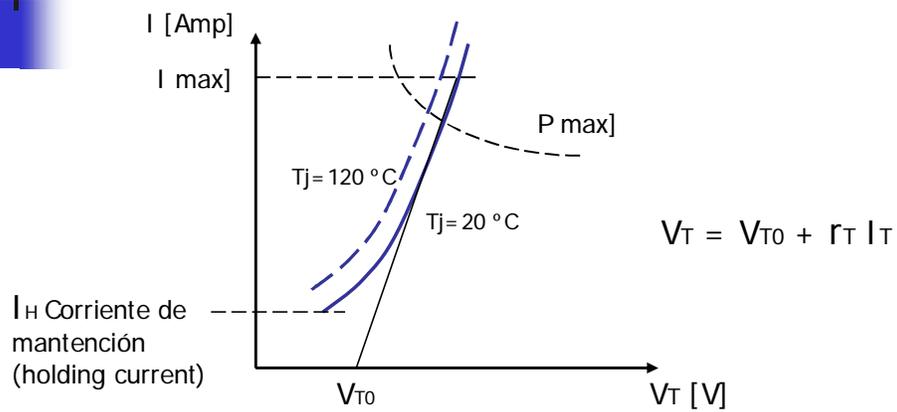
con $I_K = I_A + I_G$

$$(1 - a_1 I_A) - I_{C01} = a_2 (I_A + I_G) + I_{C02}$$

luego

$$I_A = \frac{a_2 I_G + I_{C01} + I_{C02}}{1 - (a_1 + a_2)}$$

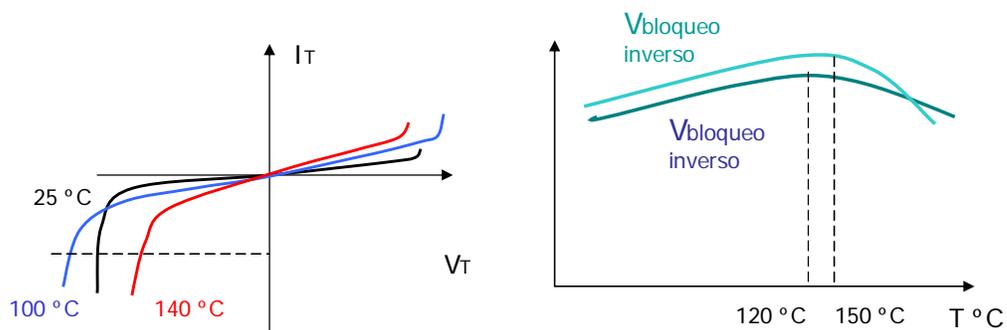
Curva característica de conducción



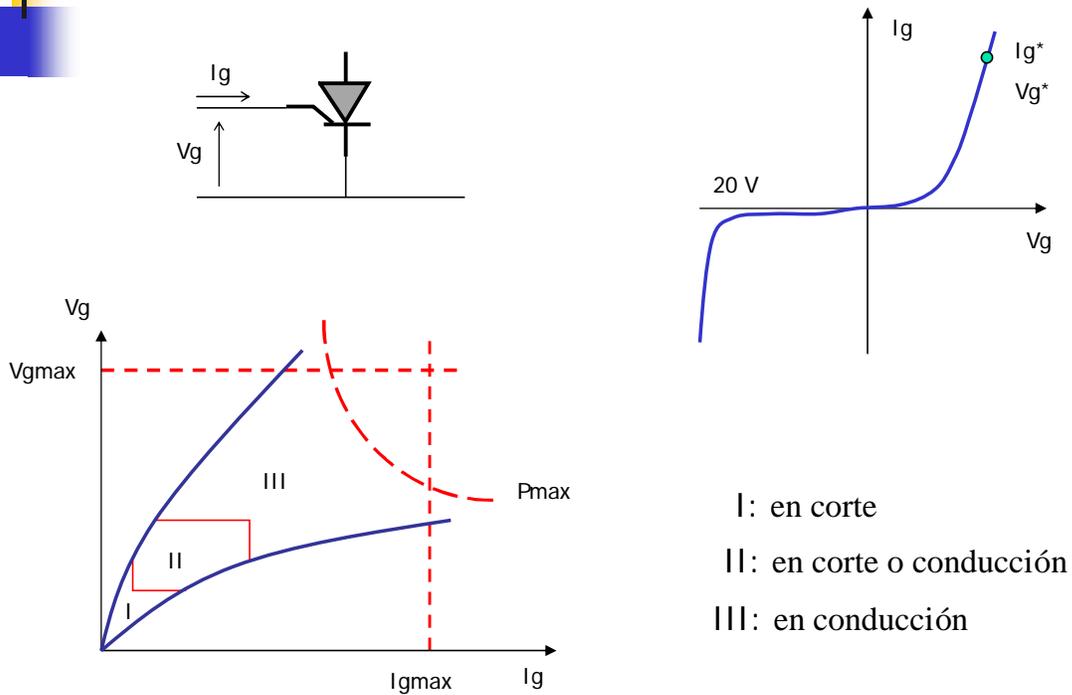
$$\begin{aligned}
 P_{max} &= 1/T \int V_T I_T dt = 1/T \int (V_{T0} + r_T I_T) I_T dt \\
 &= 1/T V_{T0} \int I_T dt + r_T 1/T \int I_T^2 dt
 \end{aligned}$$

$$P_{max} = P_{av} + r_T I_{ef}^2$$

Voltaje de bloqueo

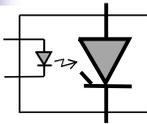


Curva característica de compuerta



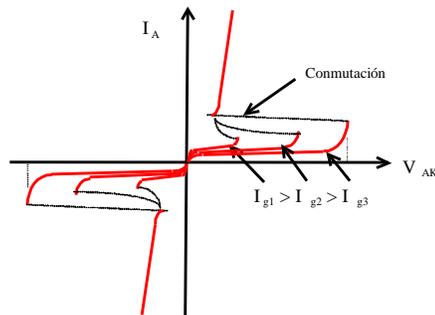
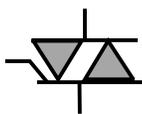
Otros dispositivos de tres junturas

Tiristor optacoplado



Al inyectar fotones en la zona de transición que soporta el bloqueo directo, se aumenta la generación de pares electrón hueco y con ello la corriente inversa. Con ello se reduce el voltaje ánodo cátodo requerido para la conmuta

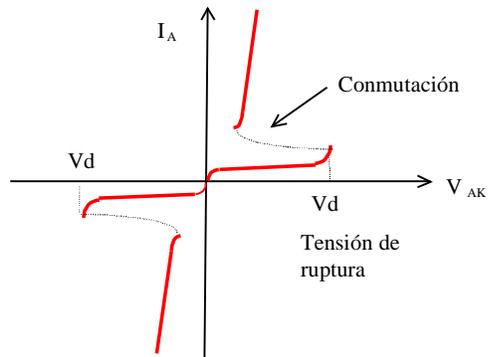
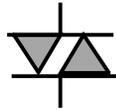
Triac



Triac: curva característica

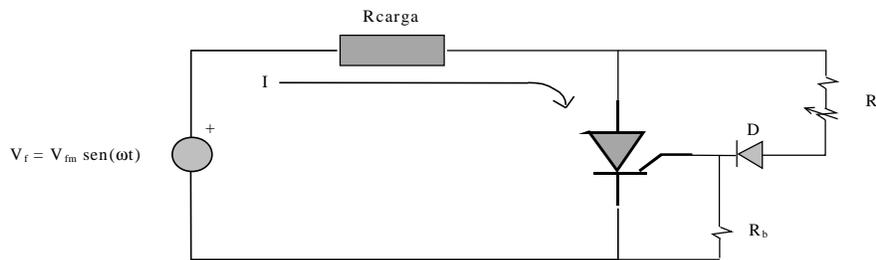
Otros dispositivos de tres juntas

Diac



Diac: curva característica

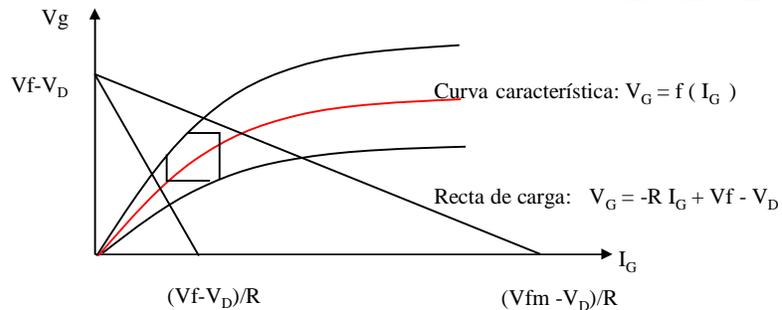
Disparo resistivo

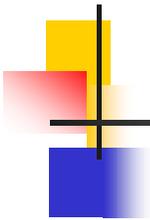


Limitación corriente de compuerta
Limitación voltaje compuerta:

$$R_{min} = (V_{fm} - V_D) / I_{GM}$$

$$R_{min} = R_b (V_{fm} - V_{GM}) / V_{GM}$$

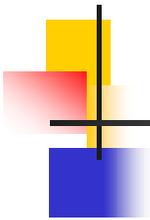
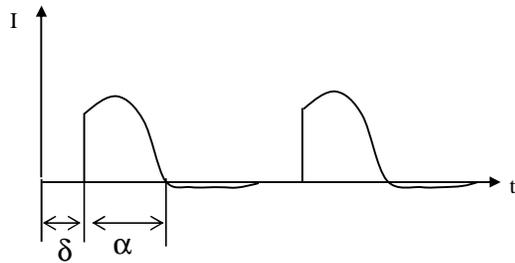




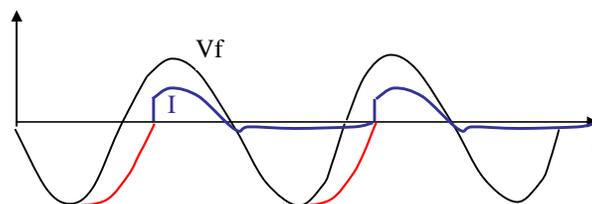
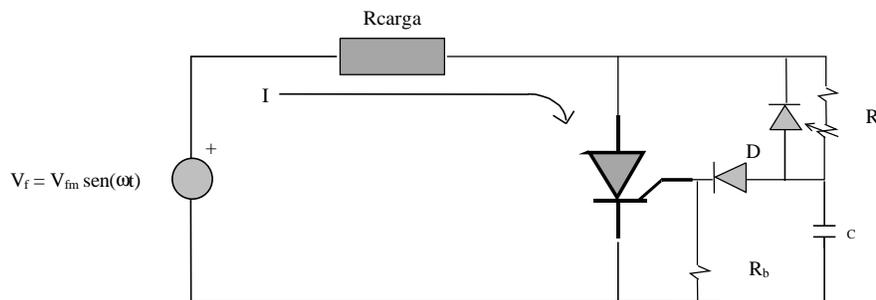
Disparo resistivo

Angulo de disparo: $\delta = [0 - 90^\circ]$

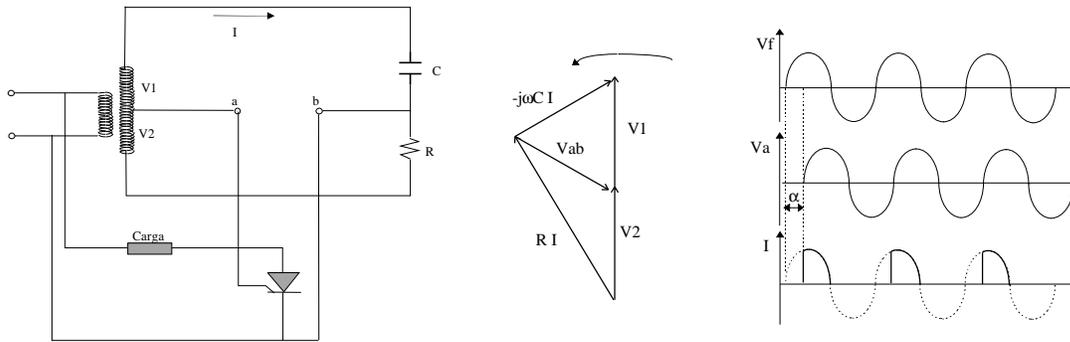
Angulo de conducción: $\alpha = [180 - 90^\circ]$



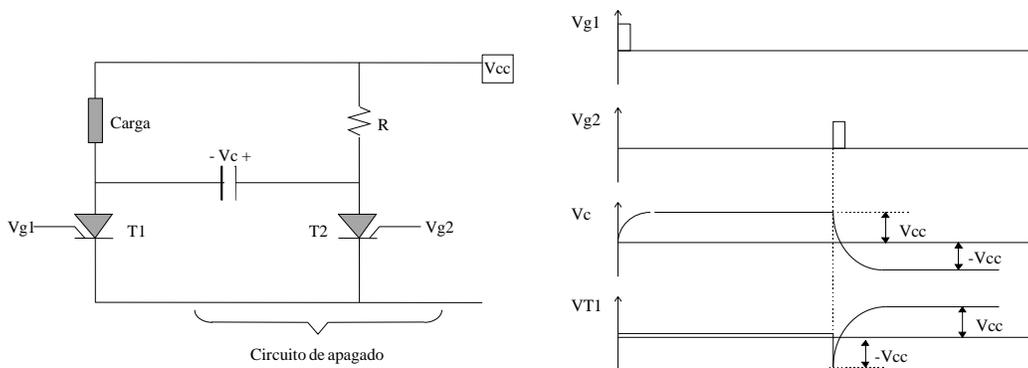
Disparo RC



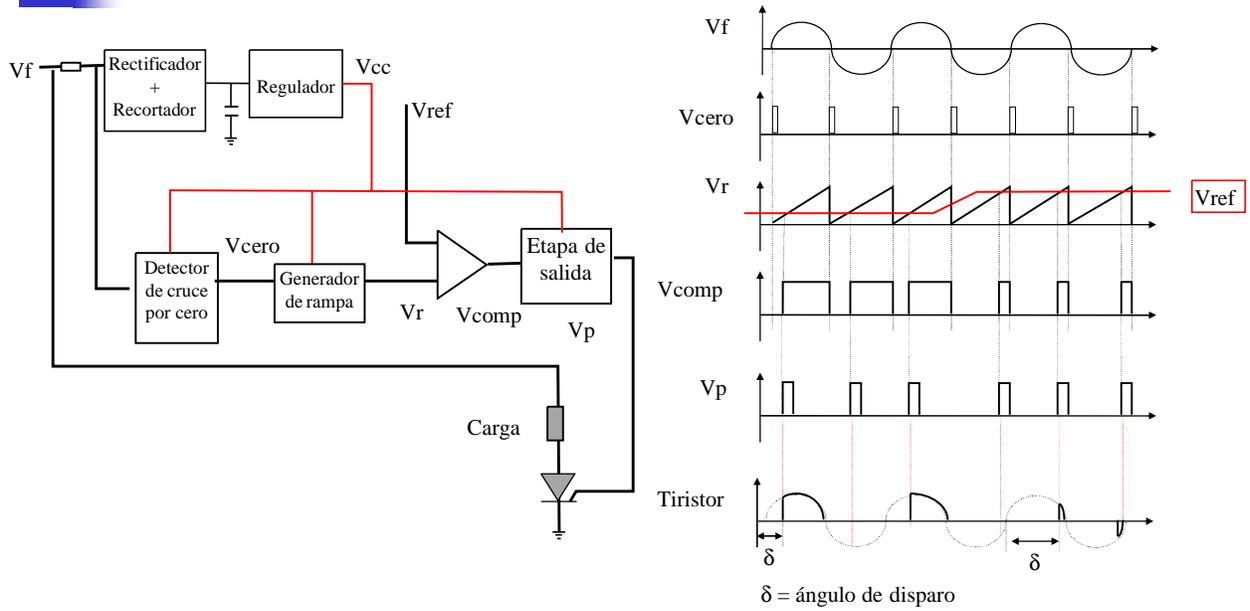
Encendido con transformador de pto. medio



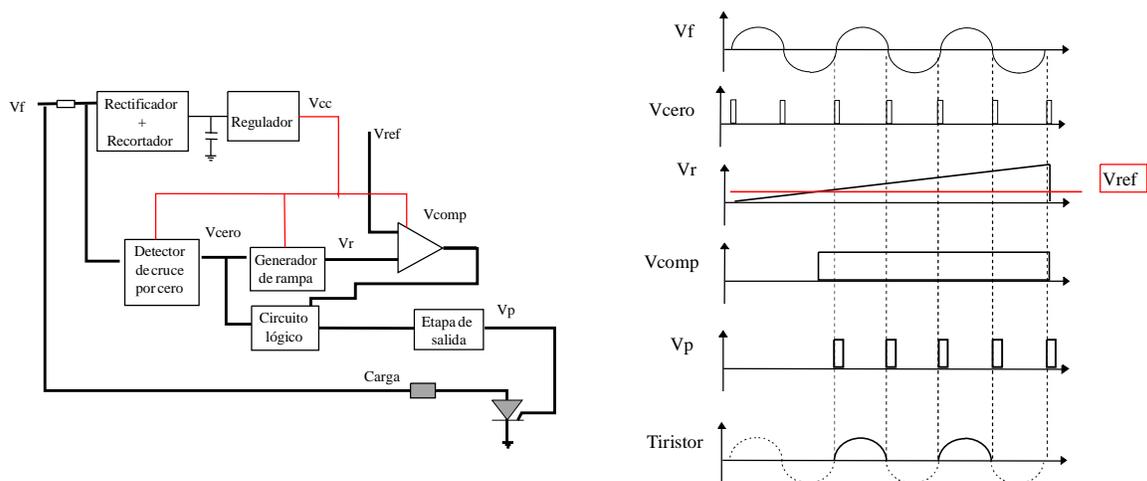
Apagado del tiristor alimentado con CC

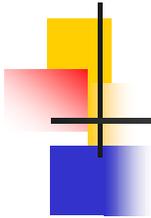


Control proporcional de fase



Control proporcional de N° de ciclos





FIN